# **WS83**



Wet tantalum capacitors

Hermetically sealed tantalum cases

Very high capacitance
Enhanced performances

SMD

Polarized

## **ELECTRICAL AND CLIMATIC CHARACTERISTICS**

	WS83
Detail specification	According to DSCC DWG No. 10004
Operating temperature	−55°C +125°C
Damp heat	MIL-STD-202 method 103 (56 days)
Capacitance range	150μF → 10 000μF
Tolerance	±10% - ±20%
Voltage range	10V ⇒ 125V
Max. capacitance change at -55°C	see table
Max. capacitance change at +85°C	see table
Max. capacitance change at +125℃	see table
Max. Impedance (100Hz) at -55°C	see table
Max. leakage current at +20°C	see table
Max. leakage current at +85°C	see table
Max. leakage current at +125°C	= lim85°C
Max. ripple current 40kHz +85°C	see table
Max. ESR at 100Hz +25°C / 40kHz +25°C	see table
Reverse voltage	No
Max. surge voltage at +85°C	1,15 x U <sub>R</sub>
Max. surge voltage at +125°C	1,15 x U <sub>C</sub>
Life test	MIL-PRF-39006 (2000 h at 85°C under rated voltage or 2000 h at 125°C under category voltage)
Low pressure	MIL-STD-202 method 105C (1,45 mbar - 45 720 m)
Shock	MIL-STD-202 method 213 (100 g)
Vibrations, high frequency	MIL-STD-202 method 204 (50 g)
Thermal shock	MIL-STD-202 method 107 ( $-55^{\circ}$ C +125 $^{\circ}$ C 30 cycles)

## DIMENSIONS (mm)

	Dimensions with insulating sleeve									
Case code	B max	F max	H max	E ±0,4	C max	G max	X max	0 max		
С	21,5	4,0	7,5	8,4	12,5	2,0	2,8	10,1		
D	29,5	4,0	7,5	8,4	12,5	2,0	2,8	10,1		

# E X F A X

## MARKING, PACKAGING, CONSTRUCTION:

see general characteristics

## **HOW TO ORDER**

Commercial	Model	Case	Capacitance in <b>µ</b> F	Tolerance in %	DC Voltage	Termination		Insulating slee	ve
description	WS83 SMD	D	10000µF	20%	10V	Н		-	
EXXELIA PN	Model code	Case	Capacitance code	Tolerance code	DC Voltage code	Termination		Insulating slee	eve
EXXELIA PN	WS83	D	109	M	010	H	Н		
			Expressed in pF with 3 digits:	<b>K</b> = 10%	Expressed in volt	EXXELIA PN	Com. description	Commercial description	EXXELIA PN
			2 digits for the value and the	M = 10%	with 3 digits	$\mathbf{H} = SnPb (non RoHS)$	$\mathbf{H} = SnPb$	- = With	S = With
			third for the multiplier	W - 20%	with 5 digits	<b>F</b> = Sn100% (RoHS)	- = Sn100%	WITHOUT SLEEVE = Without	<b>U</b> = Without



WS83

## **STANDARD RATINGS - ELECTRICAL CHARACTERISTICS**

Capacitance 100Hz +20°C	Case	Туре	Capacita	ance maximum	n change	Max. Impedance	Max	c. I leak	Irms Max. - 40kHz +85°C = (mA)	Max.	ESR
(μF)	(code)	igpe	–55℃ (%)	+85°C (%)	+125°C (%)	100Hz −55℃ (Ω)	+20℃ (µA)	+85°C / +125°C (µA)		100Hz $\{\Omega\}$	<b>40kHz</b> (Ω)
			R	ated voltage (	+85°C) 10V - (	Category voltage	(+125°C) 7V				
4700	С	WS83	-80	+10	+20	3.50	16	100	4000	0.35	0.14
10 000	D	WS83	-85	+20	+35	3.00	25	150	5000	0.25	0.10
			Ra	ated voltage (+	+85°C) 16V - C	ategory voltage (	+125°C) 11V				
3300	С	WS83	-80	+10	+15	3.50	16	100	4000	0.35	0.14
6000	D	WS83	-80	+15	+20	3.00	25	150	4500	0.30	0.12
			Ra	ated voltage (+	-85°C) 25V - C	ategory voltage (	+125°C) 15V				
2200	С	WS83	-80	+10	+15	5.50	16	100	3750	0.40	0.16
4000	D	WS83	-80	+15	+20	5.00	25	125	4250	0.35	0.14
			Ra	ted voltage (+	-85°C) <u>30V - C</u>	ategory voltage (	+125°C) 20V				
1800	С	WS83	-80	+15	+20	4.50	16	100	2100	0.45	0.18
3300	D	WS83	-80	+20	+25	4.00	25	125	2750	0.35	0.14
			Ra	ted voltage (+	-85°C) 35V - C	ategory voltage (	+125°C] 22V	1			
1500	С	WS83	-80	+15	+25	5.00	16	100	3000	0.50	0.20
2800	D	WS83	-80	+20	+30	4.50	25	125	4000	0.35	0.14
			Ra	ted voltage (+	-85°C) 50V - C	ategory voltage (	+125°C) 30\	,			
1000	С	WS83	-70	+10	+20	10.0	16	125	2450	0.95	0.38
1500	C	WS83	-80	+15	+25	8.00	15	130	2400	1.00	0.40
1500	D	WS83	-70	+20	+20	6.00	25	110	3500	0.35	0.14
2200	D	WS83	-80	+25	+30	4.50	25	125	3000	0.60	0.24
			Ra	ted voltage (+	-85°C) 60V - C	ategory voltage (	+125°C) 40\	1			
600	С	WS83	-75	+12	+15	10.0	20	120	2500	0.90	0.36
1000	D	WS83	-40	+10	+15	5.50	20	120	3500	0.50	0.20
1200	D	WS83	-70	+15	+20	6.00	20	200	3500	0.50	0.20
			Ra	ated voltage (+	-85°C) 75V - C	ategory voltage (	+125°C) 50V	,			
470	С	WS83	-45	+10	+25	10.0	25	100	3000	0.60	0.24
750	D	WS83	-35	+10	+15	6.50	20	120	3500	0.50	0.20
1000	D	WS83	-65	+12	+20	8.00	20	200	3500	0.60	0.24
			Ra	ted voltage (+	85°C) 100V - (	Category voltage	(+125°C) 65	V			
220	С	WS83	-55	+10	+15	18.0	5	25	2500	1.40	0.56
400	D	WS83	-40	+6	+12	15.0	10	120	3000	0.70	0.28
470	D	WS83	-50	+10	+20	10.0	25	250	3500	0.70	0.28
			Ra	ted voltage (+	85°C) 125 <u>V - (</u>	Category voltage	(+125°C) <u>85</u>	V			
150	С	WS83	-50	+10	+15	25.0	5	25	2000	1.10	0.44
240	D	WS83	-35	+6	+12	20.0	15	150	2500	0.80	0.32
330	D	WS83	-55	+8	+12	15.0	25	250	2500	0.80	0.32





#### **CAPACITANCE**

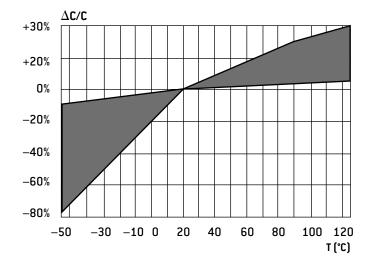
The capacitance is defined by a rated value ( $C_R$ , indicated on the capacitor) and a tolerance (generally  $\pm 20\%$ ).

The capacitance is measured at a 100Hz or at a 120Hz frequency under a 0,1 to 1  $V_{AC}$  voltage and a 2,1 to 2,5 V bias (or 9 to 10 V for  $U_R \ge 100$  V).

At room temperature, it must be in the range defined by the rated value and the tolerance.

Capacitance change vs temperature: see typical curves below. Maximum changes are given, for each type, on the data sheets.

#### **CAPACITANCE CHANGE VS TEMPERATURE**



## TOLERANCE (ON RATED CAPACITANCE)

It defines, with the rated capacitance, the range in which the capacitance value must be at room temperature.

e.g.: Rated capacitance: 100µF

Tolerance: 20%

The measured capacitance must be between:

 $100 - (20\% \text{ of } 100) = 80\mu\text{F} \text{ and } 100 + (20\% \text{ of } 100) = 120\mu\text{F}$ 

The standard tolerance for tantalum capacitors is 20%.

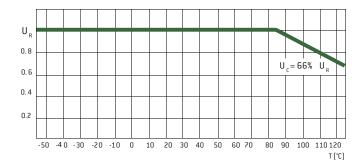




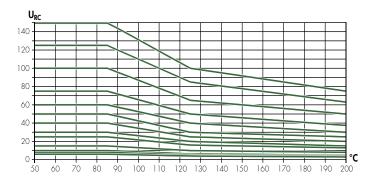
#### DIRECT DC VOLTAGE

The rated voltage  $\{U_R\}$ , indicated on the capacitor, is the maximum DC voltage which can be applied continuously between  $-55^{\circ}$ C and  $+85^{\circ}$ C.

For the types which can be used up to  $125^{\circ}$ C, the voltage must be derated between  $+85^{\circ}$ C and  $+125^{\circ}$ C according to the following curve.



For the types which can be used up to  $200^{\circ}$ C, the voltage must be derated between +85°C and +200°C according to the following curve.



The category voltage ( $U_c$ ) is consequently the maximum DC voltage which can be applied continuously at +125°C.

The surge voltage is the maximum voltage which can be applied for short periods.

It is given for each type in the data sheet and is generally equal to 1,15 times  $U_R$  between  $-55^{\circ}$ C and  $+85^{\circ}$ C and 1,15 times  $U_C$  at  $+125^{\circ}$ C.

Tests are performed with charging periods of 30 seconds, through a 1000  $\Omega$  resistor, and discharging periods of 5 min 30s. 1000 cycles are done.

#### **REVERSE VOLTAGE**

Capacitors in silver cases (CT4, CT4E, CT9, CT9E) and some in tantalum cases (WT83, WS83) cannot withstand any reverse voltage: it would cause damage, more or less rapidly depending upon the voltage value.

It is therefore necessary to be sure that the bias voltage is high enough to avoid that the AC voltage creates a reverse voltage (negative peak).

Other capacitors in tantalum cases (CT79, CT79E, ST79, DSCC 93026, M39006/22 and M39006/25) can withstand a reverse voltage as specified in the individual datasheet.

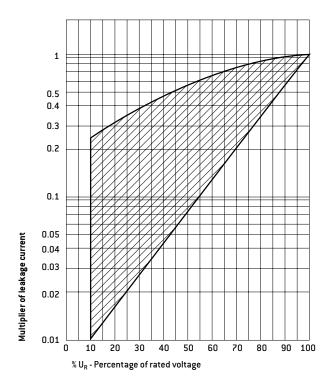
#### LEAKAGE CURRENT

Leakage current is the residual current which flows through the capacitor after the charging time, under rated voltage. It is measured after a time not exceeding 5 minutes and is given in  $\mu$ A.

It is equivalent to the insulation resistance of the capacitor and it must be as low as possible.

Maximum leakage current is a function of capacitance and rated voltage values and is given, for each type, in the data sheets.

#### LEAKAGE CURRENT CHANGE VS APPLIED VOLTAGE





#### **DISSIPATION FACTOR**

Dissipation factor is generally measured at the same time as the capacitance, with the same conditions. It is a function of the series resistance of the capacitor and the capacitance at low frequency.

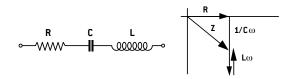
#### DF = ESR x C x 2 $\pi$ f

At low frequency, the series resistance is the sum of an ohmic part (leads, contacts,  $MnO_2$ ) and the dielectric losses.

Dissipation factor is given in % and maximum limits are given for each type in the data sheets.

#### **EQUIVALENT SERIES RESISTANCE OR IMPEDANCE**

Equivalent circuit of a capacitor



- R: equivalent series resistance of the capacitor (leads,contacts,  $MnO_2$ , dielectric losses)
- L: inductance mainly due to the leads
- C: capacitance

## Impedance

It is specified at 100Hz and  $-55^{\circ}\text{C}$  and the formula for impedance is:

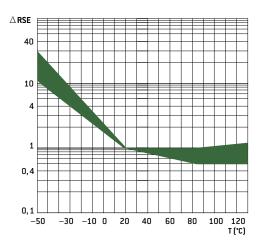
$$Z = \sqrt{R^2 + (L\omega - 1/C\omega)^2}$$

It can be seen that:

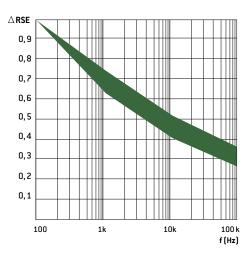
- at low frequencies, impedance is a function of capacitance
- at high frequencies, impedance is a function of inductance
- at medium frequencies, it is a function of the ESR

Maximum impedance: see data sheets.

#### **ESR CHANGE VS TEMPERATURE**



#### **ESR CHANGE VS FREQUENCY**



HERMETICALLY SEALED - TANTALUM CASES WET TANTALUM CASES

# **Electrical characteristics**

#### MAXIMUM RIPPLE CURRENT

CT79/79E (SMD) - CT79/79E HT200 - ST79 (SMD) - ST79 HT200 - WT83 - WS83

Maximum ripple currents which are indicated in the data sheets are given for the following conditions:

Temperature: +85°C (+70°C only WT82)

Frequency: 40kHz Applied voltage: 0,66

If conditions are different, use the multipliers given in the table below to calculate the new maximum current.

Frequenc	y	100Hz			1kHz			10kHz			40kHz				100kHz						
Temperatu	re	+55°C	+85°C	+105°C	+125°C	+55°C	+85°C	+105°C	+125°C	+55℃	+85°C	+105°C	+125°C	+55℃	+85°C	+105°C	+125°C	+55℃	+85°C	+105°C	+125°C
	66%	0,6	0,6	0,46	0,27	0,72	0,72	0,55	0,32	0,88	0,88	0,68	0,4	1	1	0,77	0,45	1,1	1,1	0,85	0,5
	70%	0,6	0,58	0,44	-	0,72	0,7	0,52	-	0,88	0,85	0,64	_	1	0,97	0,73	-	1,1	1,07	0,8	_
Peak voltage in % of U <sub>P</sub>	80%	0,6	0,52	0,35	-	0,72	0,62	0,42	-	0,88	0,76	0,52	_	1	0,87	0,59	-	1,1	0,96	0,65	-
% G. G <sub>R</sub>	90%	0,6	0,46	-	-	0,72	0,55	-	-	0,88	0,67	_	_	1	0,77	-	-	1,1	0,85	-	_
	100%	0,6	0,39	_	_	0,72	0,45	_	-	0,88	0,55	-	_	1	0,63	_	-	1,1	0,69	_	_

#### CT4 - CT4E - CT9 - CT9E TYPES

Maximum ripple currents which are indicated in the data sheets are given for the following conditions:

- frequency from 100Hz to 100kHz and more
- temperature from  $-55^{\circ}$ C to  $+85^{\circ}$ C

#### Correction vs temperature

If the temperature is higher than 85°C, decrease linearly the maximum value from 100% at +85°C to 80% at +125°C.

#### Correction vs frequency

If frequency is lower than 100Hz, apply the following multipliers to the maximum ripple currents:

**75Hz:** 0,79 **60Hz:** 0,65 **50Hz:** 0,55 **25Hz:** 0,55

#### OTHERS RULES (FOR ALL TYPES)

- the sum of the positive peak AC voltage and the DC bias voltage must be lower than the rated voltage.
- the negative peak must not create any Reverse voltage (or maximum 3 volts for CT79 and CT79E types).
- because of the increase of the series resistance at low temperature, it is better to not apply directly the maximum ripple current but to increase this one gradually to raise the capacitor temperature.

#### **CLIMATIC CHARACTERISTICS**

#### 1- CLIMATIC CATEGORY

Climatic category defines the temperature range over which the capacitor can be used continuously, and also the number of days for the damp heat test [this test is performed periodically at 40°C with a 93% moisture rate].

**Note:** it is necessary to derate the voltage for temperatures higher than  $85^{\circ}$ C (see page 15).

#### 2- THERMAL SHOCKS - RAPID CHANGES OF TEMPERATURE

This test is performed to check that the capacitors can withstand sudden temperature changes. The method which is used is the one with two chambers, one at  $-55^{\circ}$ C, the other one at  $+125^{\circ}$ C. Five cycles are performed, with 30min at low temperature and 30min at high temperature, during the periodical tests (30 cycles for CT79 type). Electrical characteristics are measured after this test.

#### 3 - DAMP HEAT TEST

This test is performed during the periodical test, with the following conditions:

Temperature: 40°C Humidity: 90 to 95% DC voltage: without Time: 21 or 56 days

Electrical characteristics are measured after this test.

#### MECHANICAL CHARACTERISTICS

#### 1 - VIBRATIONS

This test is performed during the periodical test, with the following conditions:

#### CT9 - CT9E types

• Frequency: 10 to 2000Hz

• Amplitude: 1,5mm or 196m/s2 - 20g

• Time: 6 hours

## CT79/79E (SMD) - CT79/79E HT200 - ST79 (SMD) - ST79 HT200 - WT83 - WS83

• Frequency: 10 to 2000Hz

• Amplitude: 3,5mm or 490m/s2 - 50g

• Time: 6 hours

#### 2 - SHOCKS

This test is performed just after the vibrations test, with the following conditions for all types:

- Acceleration: 981 m/s<sup>2</sup> 100g
- Pulse width: 6 ms
- Shape: 1/2 sinewave
- Number of shocks: 18 (3 in each direction, positive and negative)



#### RELIABILITY

Reliability of a component can be defined as its probability to work without any failure, in defined conditions and during a fixed time.

Reliability is not therefore only a function of the component quality, but also of the application and environmental conditions.

The parameter which is the most commonly used for the reliability is the failure rate in time, generally expressed in % per 1000 hours.

#### CALCULATION OF A COMPONENT FAILURE RATE USED IN AN EQUIPMENT

The calculation method on the next page uses parmeters which are given by the CNET (Centre National d'Étude des Télécommunications) in its Reliability Data Book (RDF 1993).

The failure rate is calculated with parameters which are function of the capacitor (capacitance, case type, approvals, high surge current test) and others ones which are representative of application conditions (voltage, temperature, resistance in serie, environmental conditions).

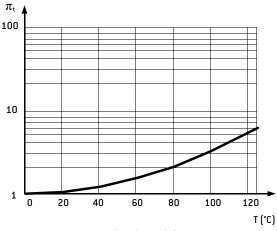
#### Example:

CT79E 2200 $\mu$ F - 6,3 V used under 3 volts, at 40°C, in a satellite in orbit:

$$\pi_{t} = 1.2 \ \pi_{V} = 1.38 \ \pi_{C} = 1.4 \ \pi_{E} = 0.5 \ \pi_{G} = 1$$

 $\lambda = 3 \times 1,2 \times 1,38 \times 1,4 \times 0,5 \times 1.10^{-9}/h = 3,5.10^{-9}/h = 0,00035 \%$  defects/1000 hours

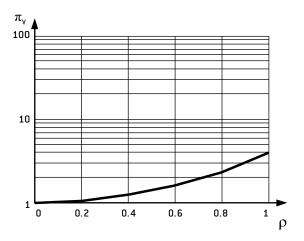
#### $\pi_{\star}$ = TEMPERATURE INFLUENCE



Formula:  $\pi_t = \exp(1,8.(t/tm)^2)$ with: t = using temperaturetm = maximum temperature

tm = maximum tempera Curve for tm =  $125^{\circ}$ C

#### $\pi_{v}$ = influence of applied voltage vs rated voltage



Formula:  $\pi_{v} = \exp((\rho / 0.85)^{2})$ 

$$\rho = \frac{\text{peak voltage}}{\text{rated voltage}}$$

Curve  $\pi_v = f(\rho)$ 

#### $\pi_c$ = influence of capacitance

3,3 <i>µ</i> F	$oldsymbol{\pi}_{ extsf{c}}$ = 0,9
20μF	$oldsymbol{\pi}_{ extsf{C}}$ = 1,0
1000μF	$oldsymbol{\pi}_{ extsf{C}}$ = 1,3
2200UE	$\pi_c = 1.4$

#### $\pi_{\rm E}$ = influence of application

Satellite in orbit	$oldsymbol{\pi}_{\scriptscriptstyle  extsf{E}}$ = 0,5
Ground; stationary; protected	$oldsymbol{\pi}_{E}$ = 1
Ground; stationary; non protected	$oldsymbol{\pi}_{E}$ = 2,5
Ground; mobile; soft conditions	$oldsymbol{\pi}_{\scriptscriptstyle{E}}$ = 6
Aircraft; soft conditions	$oldsymbol{\pi}_{\scriptscriptstyle E}$ = 6
Ship; soft conditions	$oldsymbol{\pi}_{\scriptscriptstyle{E}}$ = 6
Ground; mobile; hard conditions	$oldsymbol{\pi}_{\scriptscriptstyle E}$ = 8
Ship; hard conditions	$oldsymbol{\pi}_{E}$ = 10
Aircraft; hard conditions	$oldsymbol{\pi}_{\scriptscriptstyle  extsf{E}}$ = 15
Satellite; launching	$oldsymbol{\pi}_{E}$ = 20

#### $\pi_{a}$ = influence of qualification

Products approved to CECC	$oldsymbol{\pi}_{ extsf{q}}$ = 1,0
Others products	$\pi_{\alpha}$ = 2,0

#### PRODUCT SAFETY INFORMATION SHEET

This should read in conjunction with the Product Data Sheet/Specification.

Failure to observe the ratings, and the information on this sheet may result in a safety hazard.

#### 1. MATERIAL CONTENT

Wet tantalum capacitors contain hazardous materials:

- Liquid electrolyte gelled diluted sulphuric acid
- Solid tantalum anode

The device consists of solder coated terminal wires and the materials listed below:

- Silver case or tantalum case
- Rubber "o" rings
- PTFE spacers
- Filled epoxy resin end cap on silver case products

#### 2. PHYSICAL FORM

These Capacitors are physically small and are cylindrical with axial leads.

#### 3. INTRINSIC PROPERTIES

#### 3.1 Operating

Wet tantalum capacitors will operate satisfactorily providing that the sum of the applied d.c. and the peak a.c. ripple voltage does not exceed the rated d.c. voltage. There must be no reversal of polarity.

The maximum ripple currents and voltages and d.c. polarising voltages are specified in the data sheets.

Some tantalum cased devices will stand up to 3  $V_{\text{DC}}$  Reverse for short periods of

A Reverse application of the rated voltage will result in loss of capacitance, early short circuit failure and may result in fire or explosion.

It may also cause consequential failure of other associated components in circuit, e.g. diodes, transformers, etc.

#### 3.2 Non-Operating

Wet Tantalum capacitors contain electrolyte which is a conducting material.

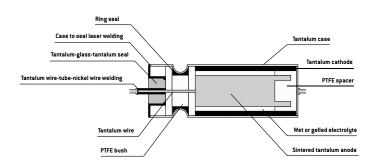
If electrolyte leaks onto a printed circuit board or similar insulated support, short circuits can be caused.

All electrolytes are corrosive to some extent.

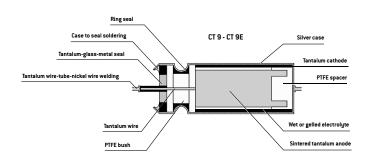
No electrolyte should be allowed to come in contact with the skin, eyes, etc., and if they do appropriate medical treatment should be applied.

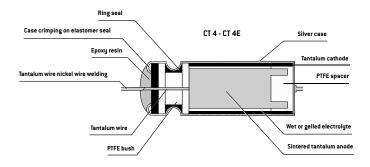
#### CONSTRUCTION

CT79/79E (SMD) - CT79/79E HT200 - ST79 (SMD) - ST79 HT200 - WT83 - WS83

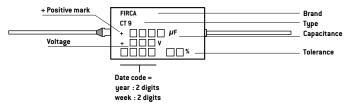


Glass metal seal: CT9 - CT9E Epoxy sealing: CT4 - CT4E





MARKING (except DSCC 93026, M39006/22, M39006/25)



#### **PACKAGING**

In cardboard boxes



# **General information**

Tantalum capacitors are, with ceramic, aluminum and film capacitors, one of the most used family.

The manufacturing technology and the constant improvements in tantalum powders allow it to be the capacitor with the highest CV (product capacitance x voltage) per volume, very long life and high reliability.

It has also the following advantages:

- Wide range of capacitance (less than  $1\mu$ F to more than  $10\,000\mu$ F)
- Wide operating temperature range (-55°C to +200°C)
- Electrical characteristics stable with temperature
- Low leakage current
- Very low ESR for some types
- · Stability after long periods of storage, without any reforming

All these characteristics allow tantalum capacitors to be commonly used either in large volume markets like mobile phones or computers, or in specific High-Rel applications such as space, aerospace and military.

Its main uses are found in the following functions:

Filtering

• RC time constant

• Bypass

Energy storage

Wet tantalum capacitors:

Tantalum cases

Silver cases

Coupling

Tantalum capacitors can be divided into two main families and several subfamilies:

#### Solid tantalum capacitors:

#### Solid Mn0<sub>2</sub>

- Metal cases
- Molded cases
- SMD
- Solid Polymer
  - SMD

#### HOW TO USE THE SELECTION GUIDE

- 1 The **Technical Selection Guide** can be used to select a product according to the main technical requirements.
- 2 The Classification according to specification makes the link between all major standard specifications and the products.
- 3 The Selection Guide by family has the same classification as in the catalogue. You will find for each type the main features, the approvals and the page number of the technical data sheet.

#### **MANUFACTURING**

#### ANODE AND INSULATOR

Tantalum capacitors are the capacitors which have the highest ratio of capacitance per volume. This is mainly due to the high dielectric coefficient of its insulator and to its large cross-section.

The basic raw material is a high purity (greater than 99,99%) tantalum powder with a very fine granulation, compressed to form a cylinder or a parallelipiped constituting the anode of the capacitor (positive plate).

The pellet is then sintered at high temperature ( $1200^{\circ}$ C to  $2200^{\circ}$ C), under high vacuum ( $10^{-6}$  Torr), firstly to purify the powder and secondly to obtain a strong mechanical structure by a welding of the particles.

The insulating part is obtained by anodization to a depth of the tantalum surface which forms a tantalum pentoxide film  $\{Ta_20_5\}$  with a thickness of about 16 angstroms per anodization volt. The dielectric coefficient is between 21 and 27 depending upon the anodization conditions.

#### WET ELECTROLYTE: CATHODE AND ENCAPSULATION

In this case, the cathode is formed by a sulphuric acid solution. The anodized tantalum pellet is impregnated with this solution and then placed in a silver or tantalum case, into which some equivalent gelled solution have been previously deposited.

The case is then crimped on the internal PTFE gasket to make the sealing. The final steps are welding (CT79), soldering (CT9) or elastomer seal (CT4) depending on the capacitors.

#### SOLID ELECTROLYTE: CATHODE AND ENCAPSULATION

In this case, the cathode is formed either by managanous dioxide which is a grey semi conductor or by polymer solution.

Solid  $MnO_2$  cathode is obtained by dipping the pellets into a manganous nitrate water solution which impregnates the internal structure; this solution is then decomposed in a high temperature oven to obtain manganous dioxide. This operation is repeated several times. The nature and quality of this semiconductor are important to some of the electrical parameters (especially the serial resistance).

To finish the negative plate, a graphite coating and then a silver coating are deposited on the outside surface of the manganous dioxide or conducting polymer.

The positive nickel lead is welded on the tantalum wire and the negative lead is either soldered for the products with axial leads or glued with a silver epoxy for the SMD range.

#### **BURN-IN - SORTING - INSPECTION**

All the products are submitted to a final burn-in, with differing severities depending upon the characteristics of each type (temperature, voltage, duration).

Then follows the sorting, marking and inspection operations. It can be noted that the procedures for these operations are the same for approved and non approved parts (except the periodical tests).



# General information

#### **TYPE IDENTIFICATION - ORDERING INFORMATION**

#### THE COMPLETE IDENTIFICATION OF A PRODUCT IS MADE OF

- The type (or model)
- The tolerance
- The case size
- The rated voltage
- The rated capacitance
- If applicable the CECC specification number

#### THE TYPE

It can be expressed with the commercial description (CTC21E C  $33\mu$ F 10% 40V) or the **EXXELIA** part number (TS22EC336K040F).

When applicable the CECC specification number should be indicated.

#### THE CASE SIZE

It is indicated on the technical data sheets in front of each capacitance-voltage value and is generally identified by a letter code. It is important to give this information because there can be, for the same type, a standard range and an extended range in which the same value will be available in two different sizes.

#### THE RATED CAPACITANCE

It can be expressed:

- Directly in  $\mu$ F (eg: 47 $\mu$ F)
- Coded according to MIL specification, with:
  - 2 digits number for the value
  - A multiplying factor to obtain the capacitance in pF (power of 10)

**Eg:**  $567 = 56.10^7 \text{ pF} = 560 \mu\text{F}$ 

#### THE TOLERANCE

It can be expressed directly in % or identified by a code letter:

 $M = \pm 20\%$ 

 $K = \pm 10\%$ 

 $J = \pm 5\%$ 

**N.B.:** the standard tolerance for tantalum capacitors is 20%; if no tolerance is specified, it would be considered as 20%.

A 20% tolerance means in fact -20% to +20%.

#### THE RATED VOLTAGE

It is expressed directly in volts (V)

**N.B.:** 6,3V rated voltage can be coded as 6V.

#### **CECC SPECIFICATIONS**

Some of the products which are described in this catalogue are made to a CECC specification; these documents give in detail the following information for each type:

- The climatic, electrical and mechanical characteristics
- The test and inspection procedures
- The sampling methods and levels
- The tests periods

The reference specifications concerning the tantalum capacitors are the following:

#### CECC 30 000 (NFC 83-100)

Generic specification: fixed capacitors

- Terminology
- Quality Assessment Procedures
- Test and inspection methods

#### CECC 30 200 (NFC 83-112)

Sectional specification: tantalum capacitors

- Prefered characteristics
- Quality Assessment Procedures
- Test and inspection methods

#### **CECC 30 201 XXX**

Detail specifications solid tantalum capacitors

• Detailed characteristics for each type

#### **CECC 30 202 XXX**

Detail specifications wet tantalum capacitors

• Detailed characteristics for each type

## CECC 30 800 (NFC 83-113)

Sectional specification: tantalum chip capacitors

- Prefered characteristics
- Quality Assessment Procedures
- Test and inspection methods

#### **CECC 30 801 XXX**

Detail specifications tantalum chip capacitors

- Detailed characteristics for each type
- The list of all the detail specifications is given in the selection guide, with the corresponding type.

NB: Some of the products refer to specifications which are no longer published.

#### OTHER SPECIFICATIONS

In addition to CECC approvals, some of the products are qualified to MIL standard M39006/22, M39006/25, DSCC DWG No. 93026 and some others are listed in ESA (European Space Agency) Preferred Parts Lists ESCC EPPL I or II.

